NSN 5961-01-140-4369



Transistor - Page 1 of 2 View Online at https://aerobasegroup.com/nsn/5961-01-140-4369 **Inclosure Material:** Metal **Overall Length:** Between 0.320 inches and 0.468 inches **End Application:** Closed-loop 03950 **Mounting Facility Quantity: Internal Configuration:** Junction contact Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-59 **Internal Junction Configuration:** Npn **Mounting Method:** Threaded stud **Features Provided:** Hermetically sealed case **Overall Width Across Flats:** Between 0.424 inches and 0.437 inches **Thread Size:** 0.190 inches **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 80.0 breakdown voltage, collector-to-base, emitter open and 80.0 breakdown voltage, collector-to-emitter, base open and 6.0 breakdown voltage, emitter-to-base, collector open **Current Rating Per Characteristic:** Between 1.00 amperes source cutoff current and 7.00 amperes source cutoff current **Power Rating Per Characteristic:** 60.0 watts small-signal input power, common-collector **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius junction **Thread Series Designator:** Unf **Terminal Type And Quantity:** 3 tab, solder lug **Specification Data:**

N/a

Unit Of Measure:

Shelf Life:

80131-release5835 professional/industrial association specification

NSN 5961-01-140-4369

Transistor - Page 2 of 2



em			

No

Fiig:

A110a0